DESCRIPTION

The 2SC1623P~2SC1623S are available in SOT-23 Package

FEATURES

 High DC current gain: h_{FE}=200TYP (V_{CEO}=50V, I_C=100mA)

● High Voltage: V_{CEO}=50V

Available in SOT-23 Package

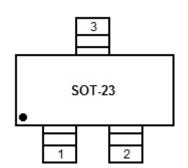
ORDERING INFORMATION

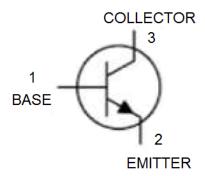
Package Type	Part Number			
SOT-23	2SC1623P			
	2SC1623Q			
	2SC1623R			
	2SC1623S			
Note	SPQ: 3,000pcs/ Reel			
AiT provides all RoHS Compliant Products				

APPLICATIONS

- NPN Silicon Epitaxial Planar Transistor
- Audio frequency general purpose amplifier

PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified

TA - 25 C, unless otherwise specified	
V _{CBO} , Collector-Base Voltage	60V
V _{CEO} , Collector-Emitter Voltage	50V
V _{EBO} , Emitter-Base Voltage	5V
Ic, Collector Current-Continuous	100mA
Pc, Collector Dissipation	200mW
T _J , T _{STG} , Junction and Storage Temperature	-55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

T_A = 25°C, unless otherwise specified

Parameter	Symbol	Characteristic		Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =100μA, I _E =0		60	-	-	>
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =1mA, I _B =0		50	-	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =100μA, I _C =0		5	-	-	V
Collector Cut-off Current	Ісво	V _{CB} =60V, I _E =0		-	-	0.1	μΑ
Emitter Cut-off Current	I _{EBO}	V _{EB} =5V, I _C =0		-	-	0.1	μΑ
DC Current Gain	hfe	V _{CE} =6V, I _C =1mA	Р	90	-	180	
			Q	135	-	270	
			R	200	-	400	
			S	300	-	600	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C =100mA, I _B =10mA		-	-	0.3	V
Transition Frequency	f⊤	V _{CE} =6V, I _C =10mA		-	250	-	MHz

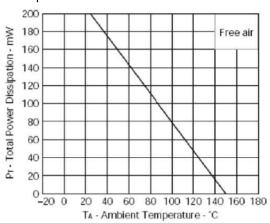


TYPICAL CHARACTERISTICS

T_A = 25°C, unless otherwise specified

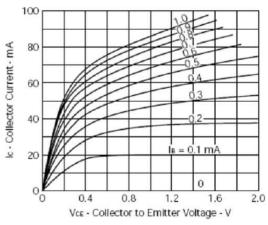
1. Total Power Dissipation vs. Ambient

Temperature

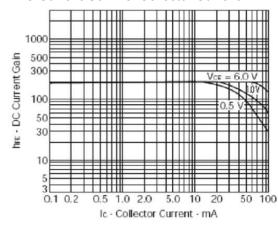


3. Collector Current vs. Collector to Emitter

Voltage

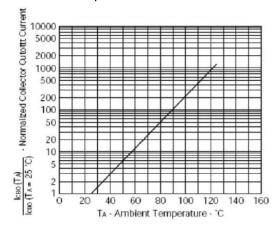


5. DC Current Gain vs. Collector Current



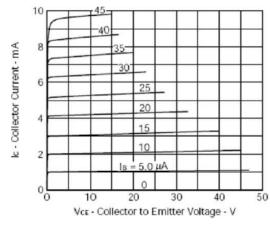
2. Normalized Collector Cutoff Current vs.

Ambient Temperature

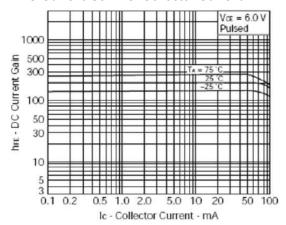


4. Collector Current vs. Collector to Emitter

Voltage

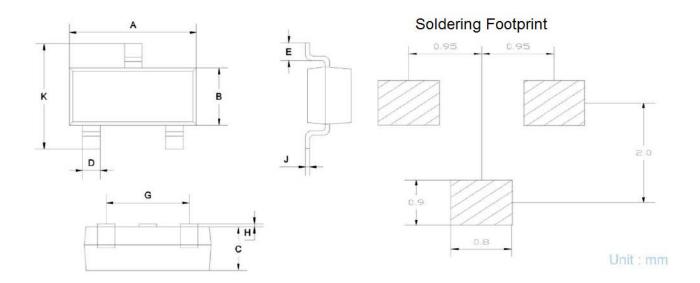


6. DC Current Gain vs. Collector Current



PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)



DIM	MIN	MAX		
А	2.85 2.95			
В	1.25	1.35		
С	1.0 TYP			
D	0.37	0.43		
Е	0.35	0.48		
G	1.85	1.95		
Н	0.02	0.1		
J	0.1 TYP			
K	2.35 2.45			

IMPORTANT NOTICE

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